

SAW Components Low-Loss Filter

B4811 188,0 MHz

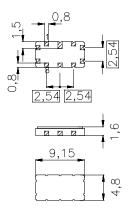
Data Sheet

Features

- Low-loss IF filter for mobile telephone
- Channel selection in GSM, PCN systems
- Ceramic SMD package

Terminals

Gold-plated Ni



SMD ceramic package QCC10B

Dimensions in mm, approx. weight 0,23 g

Pin configuration		7			
9,10 4,5 7 1,3,6,8 2	Input, balanced or unbalanced Output, balanced or unbalanced External Coil Case - Ground Not connected	40 50 1,3,6,8			

Туре	Ordering code	Marking and Package	Packing
		according to	according to
B4811	B39191-B4811-Z710	C61157-A7-A49	F61064-V8035-Z000

Electrostatic Sensitive Device (ESD)

Maximum ratings

Operable temperature range	Т	– 25 /+75	°C	
Storage temperature range	T _{stg}	- 40/+ 85	°C	
DC voltage	V _{DC}	0	V	
Source power	Ps	10	dBm	source impedance 50 Ω

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Data Sheet **Characteristics**

Operating temperature range:	Т	= -25 °C to + 75 °C
Terminating source impedance:	Z_{S}	= 580 Ω 210 nH
Terminating load impedance:	$Z_{\rm L}$	= 820 Ω 255 nH
External coil	L_{C}	= 120 nH

		min.	typ.	max.	
Center frequency	f _c	_	188,0	_	MHz
center frequency between 3 dB points)					
Minimum insertion attenuation (including matching network)		3,5	5,0	6,5	dB
Variation in insertion loss		_	1,0	3,0	dB
Amplitude ripple in passband (p-p) f _c -60,0 kHz f _c +60,0 kHz f _c -80,0 kHz f _c +80,0 kHz	Δα	_	1,0 1,5	2,0 3,0	dB dB
Group delay at f _c	τ	3,0	4,0	5,0	μs
Group delay ripple (p-p) f _c -80,0 kHz f _c +80,0 kHz	Δτ	_	1,0	1,5	μs
$ \begin{array}{l} \mbox{Relative attenuation (relative to α_{min})} \\ f_c \pm 200 \ \mbox{Hz} \ \ f_c \pm 300 \ \mbox{Hz} \\ f_c \pm 300 \ \mbox{Hz} \ \ f_c \pm 400 \ \mbox{Hz} \\ f_c \pm 400 \ \mbox{Hz} \ \ f_c \pm 600 \ \mbox{Hz} \\ f_c \pm 600 \ \mbox{Hz} \ \ f_c \pm 1,6 \ \mbox{MHz} \\ f_c \pm 1,6 \ \mbox{MHz} \ \ f_c \pm 3,0 \ \mbox{MHz} \\ f_c \pm 3,0 \ \mbox{MHz} \ \ f_c \pm 75,0 \ \mbox{MHz} \\ f_c - 12,0 \ \mbox{MHz} \end{array} $	α _{rel}	6,5 18 30 35 36 42 50	8 25 40 48 50 50 50 55		dB dB dB dB dB dB dB
Impedance at 188,0 MHz Input: $Z_{IN} = R_{IN} \parallel C_{IN}$ Output: $Z_{OUT} = R_{OUT} \parallel C_{OUT}$		_	580 3,4 820 2,8		Ω pF Ω pF
Temperature coefficient of frequency ¹⁾	TC _f	_	- 0,036		ppm/K
Turnover temperature		_	20	_	°C

¹⁾ Temperature dependance of f_c : $f_c(T) = f_c(T_0)(1 + TC_f(T - T_0)^2)$

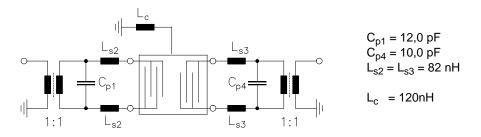
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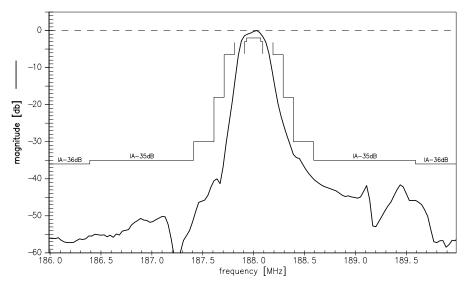


Data Sheet

Test matching network to 50 Ω (element values depend on pcb layout)



Transfer function



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